

MC33375

Advance Information Low Dropout 300 mA Voltage Regulator with ON/OFF Control

The MC33375 series are micropower low dropout voltage regulators available in a wide variety of output voltages as well as packages, SOT-223, and SOP-8 surface mount packages. These devices feature a very low quiescent current and are capable of supplying output currents up to 300 mA. Internal current and thermal limiting protection are provided by the presence of a short circuit at the output and an internal thermal shutdown circuit.

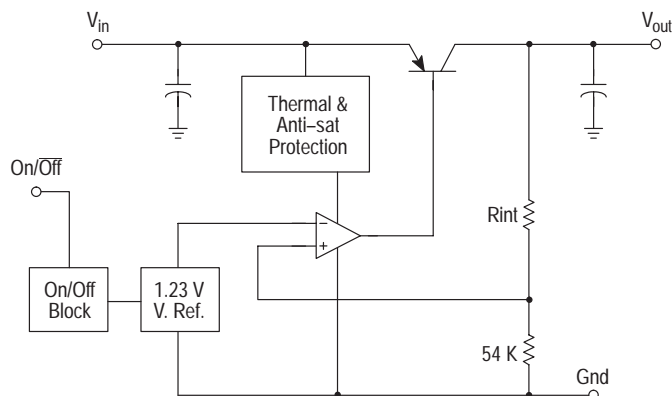
The MC33375 has a control pin that allows a logic level signal to turn-off or turn-on the regulator output.

Due to the low input-to-output voltage differential and bias current specifications, these devices are ideally suited for battery powered computer, consumer, and industrial equipment where an extension of useful battery life is desirable.

Features:

- Low Quiescent Current (0.3 μ A in OFF mode; 125 μ A in ON mode)
- Low Input-to-Output Voltage Differential of 25 mV at $I_O = 10$ mA, and 260 mV at $I_O = 300$ mA
- Extremely Tight Line and Load Regulation
- Stable with Output Capacitance of only 0.33 μ F for 2.5 V Output Voltage
- Internal Current and Thermal Limiting
- Logic Level ON/OFF Control

Simplified Block Diagram



This device contains 41 active transistors

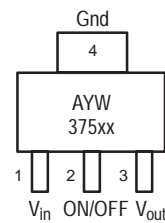
This document contains information on a new product. Specifications and information herein are subject to change without notice.



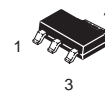
ON Semiconductor

<http://onsemi.com>

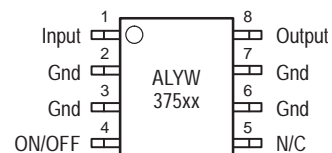
LOW DROPOUT MICROPOWER VOLTAGE REGULATOR



A = Manufacturing Code
YW = Date
xx = Version

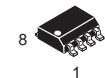


PLASTIC
ST SUFFIX
CASE 318E



Pins 4 and 5 Not Connected

AL = Manufacturing Code
YW = Date
xx = Version



PLASTIC
D SUFFIX
CASE 751

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

MC33375

ELECTRICAL CHARACTERISTICS ($C_L = 1.0\mu\text{F}$, $T_A = 25^\circ\text{C}$, for min/max values $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$, Note 1)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage $I_O = 0\text{ mA to }250\text{ mA}$ 1.8 V Suffix $T_A = 25^\circ\text{C}$, $V_{in} = [V_O + 1]\text{ V}$ 2.5 V Suffix 3.0 V Suffix 3.3 V Suffix 5.0 V Suffix 1.8 V Suffix $V_{in} = [V_O + 1]\text{ V}$, $0 < I_O < 100\text{ mA}$ 2.5 V Suffix 2% Tolerance from $T_J = -40$ to $+125^\circ\text{C}$ 3.0 V Suffix 3.3 V Suffix 5.0 V Suffix	V_O	1.782 2.475 2.970 3.267 4.950 1.764 2.450 2.940 3.234 4.900	1.80 2.50 3.00 3.30 5.00 — — — — —	1.818 2.525 3.030 3.333 5.05 1.836 2.550 3.060 3.366 5.100	Vdc
Line Regulation $V_{in} = [V_O + 1]\text{ V to }12\text{ V}$, $I_O = 250\text{ mA}$, All Suffixes $T_A = 25^\circ\text{C}$	Reg_{line}	—	2.0	10	mV
Load Regulation $V_{in} = [V_O + 1]\text{ V}$, $I_O = 0\text{ mA to }250\text{ mA}$, All Suffixes $T_A = 25^\circ\text{C}$	Reg_{load}	—	5.0	25	mV
Dropout Voltage $I_O = 10\text{ mA}$ $T_J = -40^\circ\text{C to }+125^\circ\text{C}$ $I_O = 100\text{ mA}$ $I_O = 250\text{ mA}$ $I_O = 300\text{ mA}$	$V_{in} - V_O$	— — — —	25 115 220 260	100 200 400 500	mV
Ripple Rejection (120 Hz) $V_{in(\text{peak-peak})} = [V_O + 1.5]\text{ V to }[V_O + 5.5]\text{ V}$	—	65	75	—	dB
Output Noise Voltage $C_L = 1\mu\text{F}$ $I_O = 50\text{ mA}$ (10 Hz to 100 kHz) $C_L = 200\mu\text{F}$	V_n	— —	160 46	— —	μVrms

CURRENT PARAMETERS

Quiescent Current On Mode $V_{in} = [V_O + 1]\text{ V}$, $I_O = 0\text{ mA}$ Off Mode On Mode SAT $V_{in} = [V_O - 0.5]\text{ V}$, $I_O = 0\text{ mA}$, Note 2	I_Q	— — —	125 0.3 1100	200 4.0 1500	μA
Current Limit $V_{in} = [V_O + 1]\text{ V}$, V_O shorted	I_{LIMIT}	—	450	—	mA

ON/OFF INPUTS

On/Off Input Voltage Logic "1" (Regulator On) $V_{out} = V_O \pm 2\%$ Logic "0" (Regulator Off) $V_{out} < 0.03\text{ V}$ Logic "0" (Regulator Off) $V_{out} < 0.05\text{ V}$ (1.8 V Option)	V_{CTRL}	2.4 — —	— — —	— 0.5 0.3	V
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THERMAL SHUTDOWN

Thermal Shutdown	—	—	150	—	$^\circ\text{C}$
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NOTE: 1. Low duty pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
2. Quiescent Current is measured where the PNP pass transistor is in saturation. $V_{in} = [V_O - 0.5]\text{ V}$ guarantees this condition.

DEFINITIONS

Load Regulation – The change in output voltage for a change in load current at constant chip temperature.

Dropout Voltage – The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 100 mV below its nominal value (which is measured at 1.0 V differential), dropout voltage is affected by junction temperature, load current and minimum input supply requirements.

Output Noise Voltage – The RMS AC voltage at the output with a constant load and no input ripple, measured over a specified frequency range.

Maximum Power Dissipation – The maximum total dissipation for which the regulator will operate within specifications.

Quiescent Current – Current which is used to operate the regulator chip and is not delivered to the load.

Line Regulation – The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Maximum Package Power Dissipation – The maximum package power dissipation is the power dissipation level at which the junction temperature reaches its maximum value i.e. 150°C. The junction temperature is rising while the

difference between the input power ($V_{CC} \times I_{CC}$) and the output power ($V_{out} \times I_{out}$) is increasing.

Depending on ambient temperature, it is possible to calculate the maximum power dissipation and so the maximum current as following:

$$P_d = \frac{T_J - T_A}{R_{\theta JA}}$$

The maximum operating junction temperature T_J is specified at 150°C, if $T_A = 25^\circ\text{C}$, then P_D can be found. By neglecting the quiescent current, the maximum power dissipation can be expressed as:

$$I_{out} = \frac{P_D}{V_{CC} - V_{out}}$$

The thermal resistance of the whole circuit can be evaluated by deliberately activating the thermal shutdown of the circuit (by increasing the output current or raising the input voltage for example).

Then you can calculate the power dissipation by subtracting the output power from the input power. All variables are then well known: power dissipation, thermal shutdown temperature (150°C for MC33375) and ambient temperature.

$$R_{\theta JA} = \frac{T_J - T_A}{P_D}$$

Figure 1. Line Transient Response

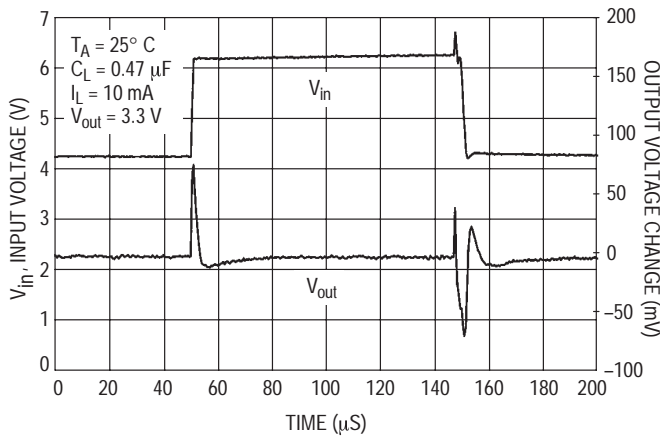


Figure 2. Line Transient Response

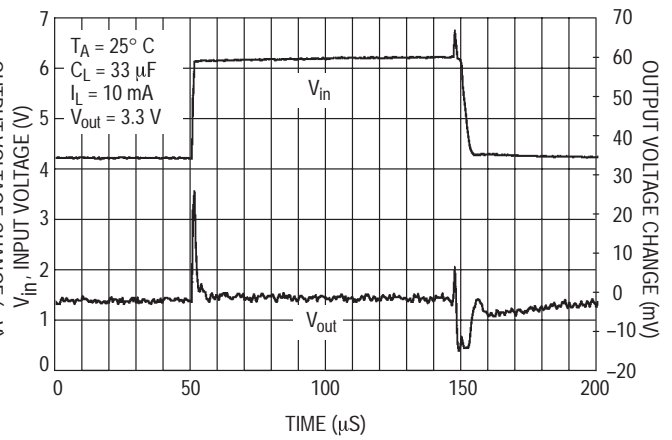


Figure 3. Load Transient Response

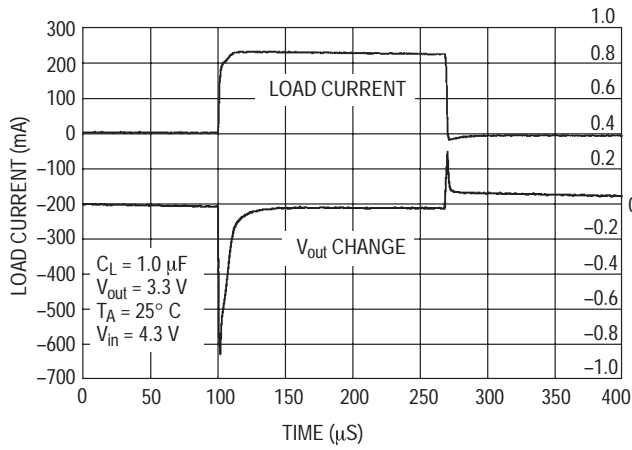


Figure 4. Load Transient Response

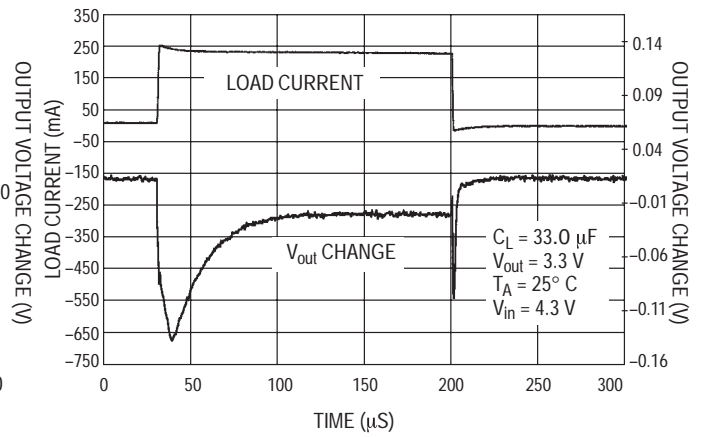


Figure 5. Output Voltage versus Input Voltage

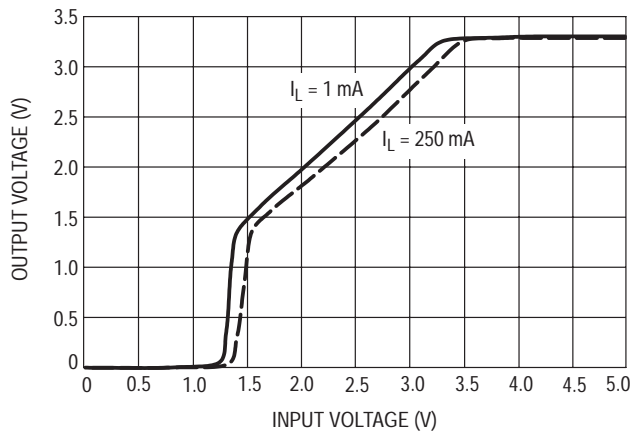


Figure 6. Dropout Voltage versus Output Current

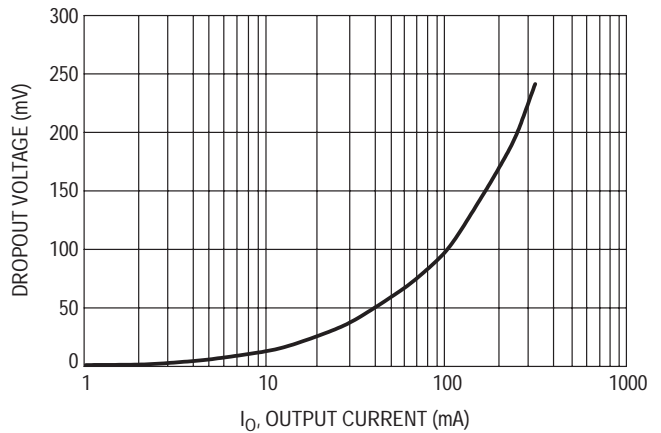


Figure 7. Dropout Voltage versus Temperature

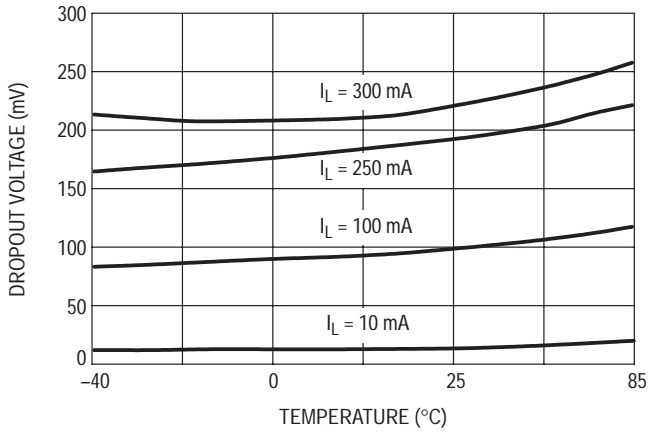


Figure 8. Ground Pin Current versus Input Voltage

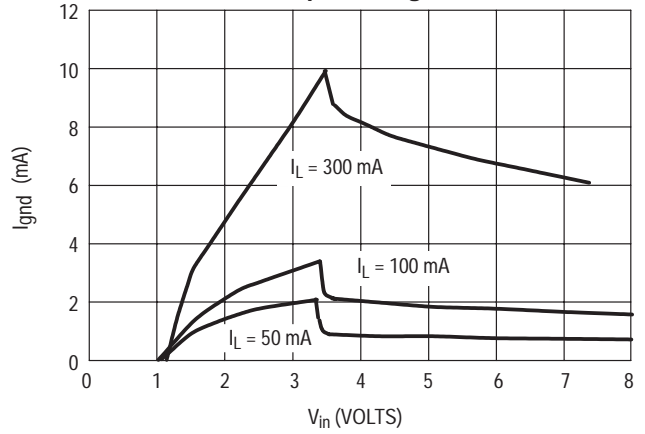


Figure 9. Ground Pin Current versus Ambient Temperature

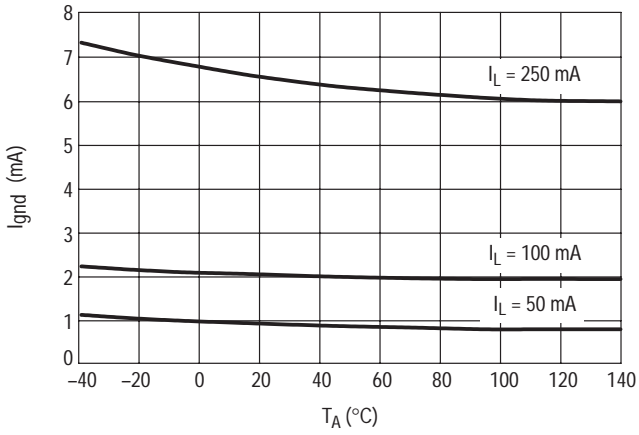


Figure 10. Output Voltage versus Ambient Temperature ($V_{in} = V_{out} + 1V$)

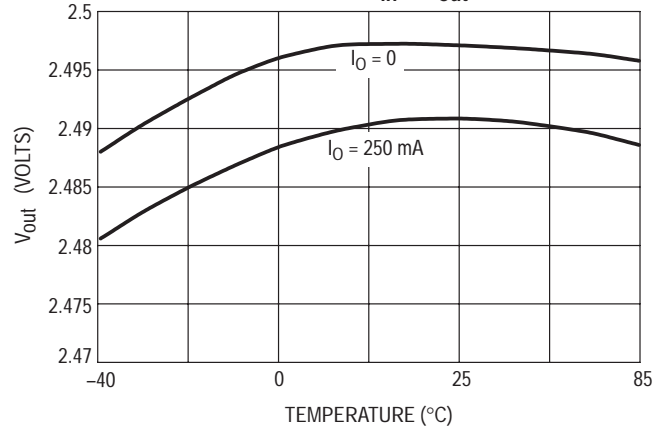


Figure 11. Output Voltage versus Ambient Temperature ($V_{in} = 12\text{ V}$)

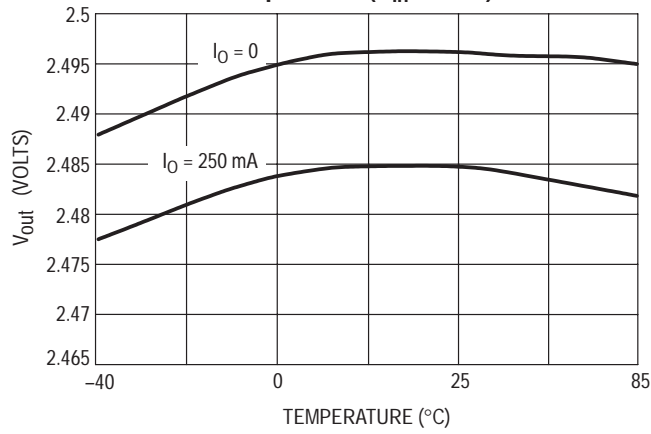


Figure 12. Ripple Rejection

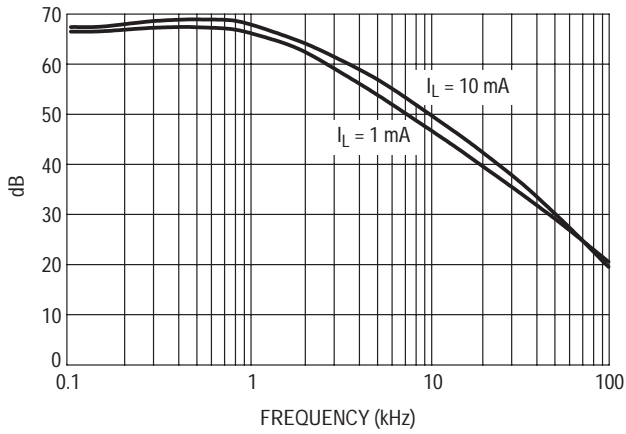


Figure 13. Ripple Rejection

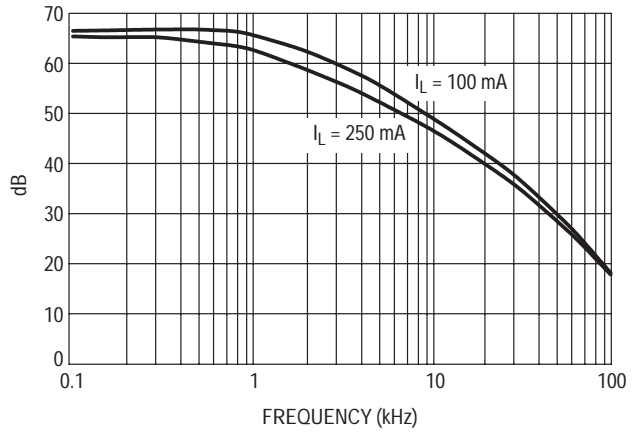


Figure 14. Enable Transient

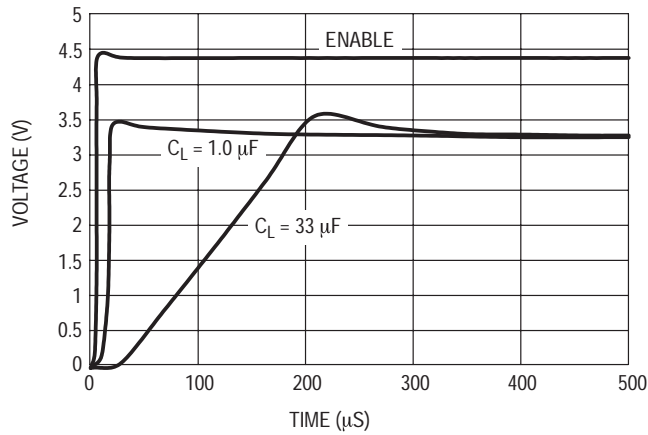


Figure 15. Output Voltage versus Temperature

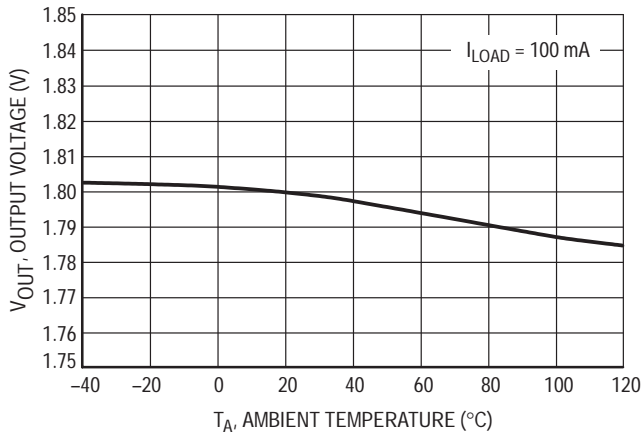


Figure 16. Output Voltage versus Input Voltage

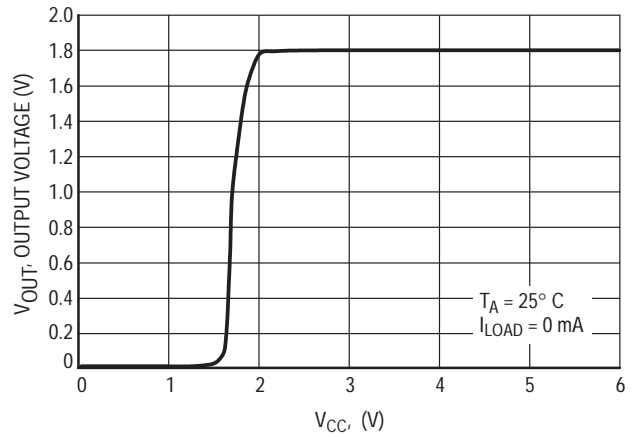


Figure 17. Ground Current versus Load Current

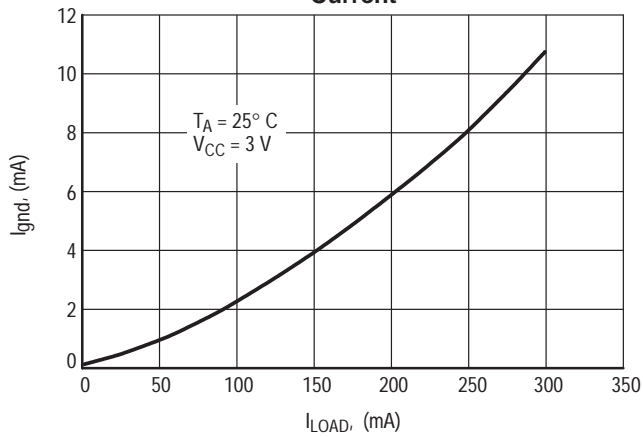


Figure 18. Quiescent Current versus Input Voltage

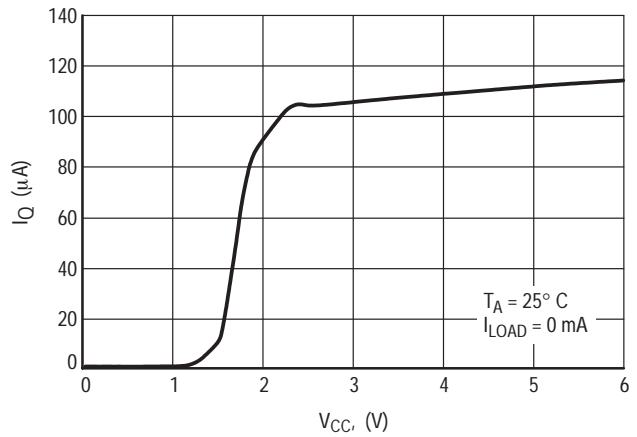


Figure 19. PSRR versus Frequency

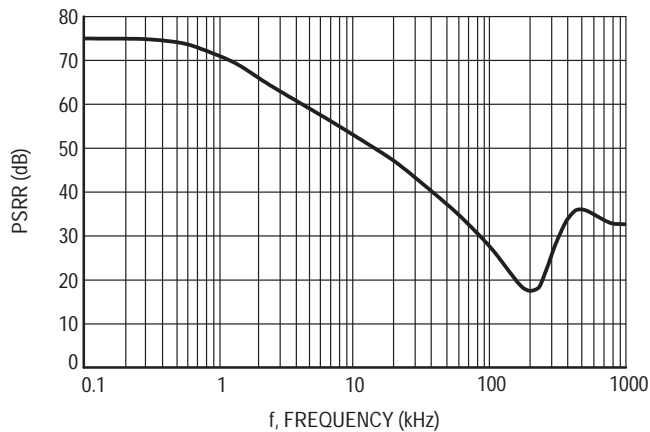


Figure 20. Enable Response

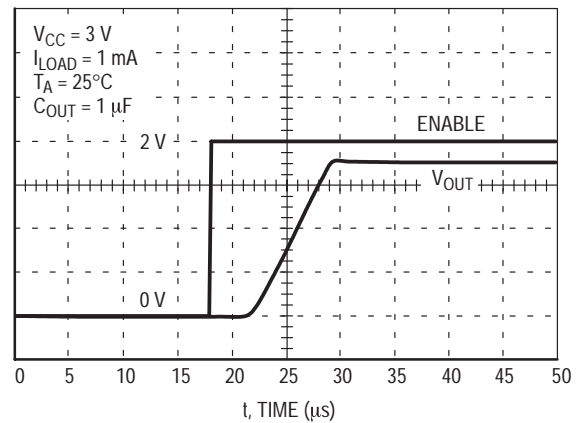
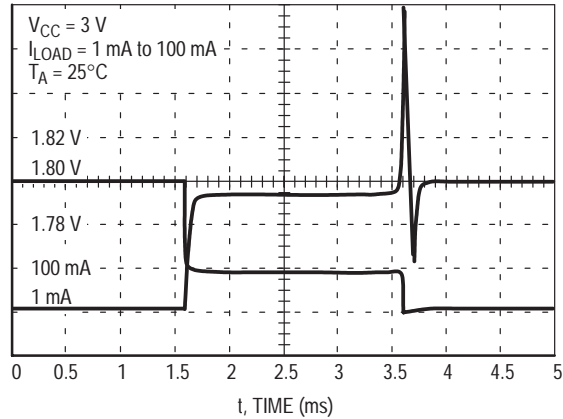
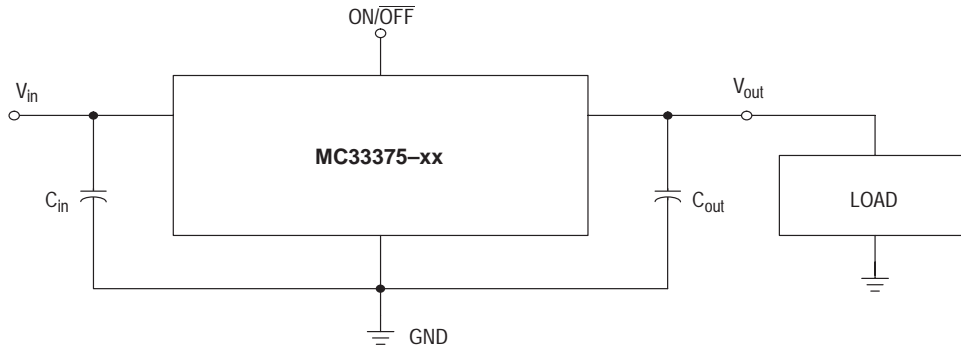


Figure 21. Load Transient Response



APPLICATIONS INFORMATION

Figure 22. Typical Application Circuit



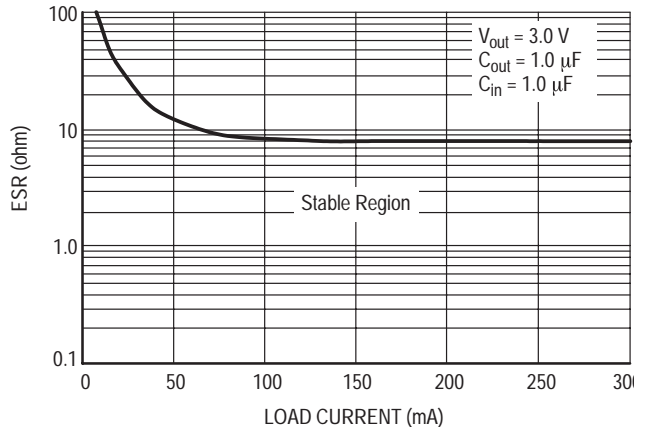
The MC33375 regulators are designed with internal current limiting and thermal shutdown making them user-friendly. Figure 15 is a typical application circuit. The output capability of the regulator is in excess of 300 mA, with a typical dropout voltage of less than 260 mV. Internal protective features include current and thermal limiting.

EXTERNAL CAPACITORS

These regulators require only a 0.33 μF (or greater) capacitance between the output and ground for stability for 1.8 V, 2.5 V, 3.0 V, and 3.3 V output voltage options. Output voltage options of 5.0 V require only 0.22 μF for stability. The output capacitor must be mounted as close as possible to the MC33375. If the output capacitor must be mounted further than two centimeters away from the MC33375, then a larger value of output capacitor may be required for stability. A value of 0.68 μF or larger is recommended. Most type of aluminum, tantalum, or multilayer ceramic will perform adequately. Solid tantalums or appropriate multilayer ceramic capacitors are recommended for operation below 25°C. An input bypass capacitor is recommended to improve transient response or if the regulator is connected to the supply input filter with long wire lengths, more than 4 inches. This will reduce the circuit's sensitivity to the input line impedance at high

frequencies. A 0.33 μF or larger tantalum, mylar, ceramic, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with shortest possible lead or track length directly across the regulator's input terminals. Figure 16 shows the ESR that allows the LDO to remain stable for various load currents.

Figure 23. ESR for $V_{\text{out}} = 3.0\text{V}$



Applications should be tested over all operating conditions to insure stability.

THERMAL PROTECTION

Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated, typically at 150°C, the output is disabled. There is no hysteresis built into the thermal protection. As a result the output will appear to be oscillating during thermal limit. The output will turn off until the temperature drops below the 150°C then the output turns on again. The process will repeat if the junction increases above the threshold. This will continue until the existing conditions allow the junction to operate below the temperature threshold.

Thermal limit is not a substitute for proper heatsinking.

The internal current limit will typically limit current to 450 mA. If during current limit the junction exceeds 150°C, the thermal protection will protect the device also. **Current limit is not a substitute for proper heatsinking.**

OUTPUT NOISE

In many applications it is desirable to reduce the noise present at the output. Reducing the regulator bandwidth by increasing the size of the output capacitor will reduce the noise on the MC33375.

ON/OFF PIN

When this pin is pulled low, the MC33375 is off. This pin should not be left floating. The pin should be pulled high for the MC33375 to operate.

Figure 24. SOT-223 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

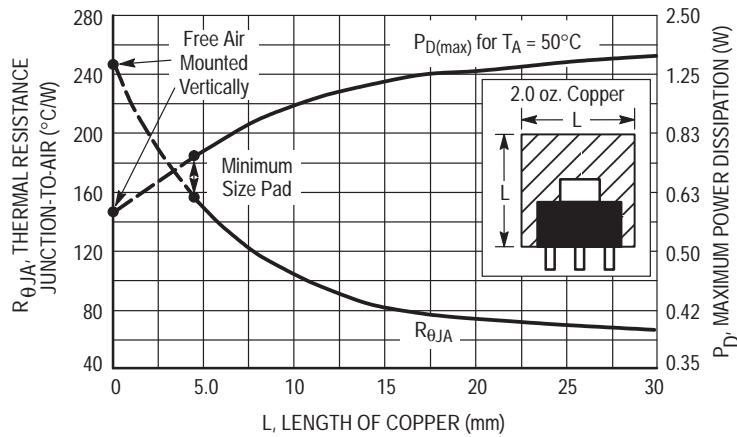
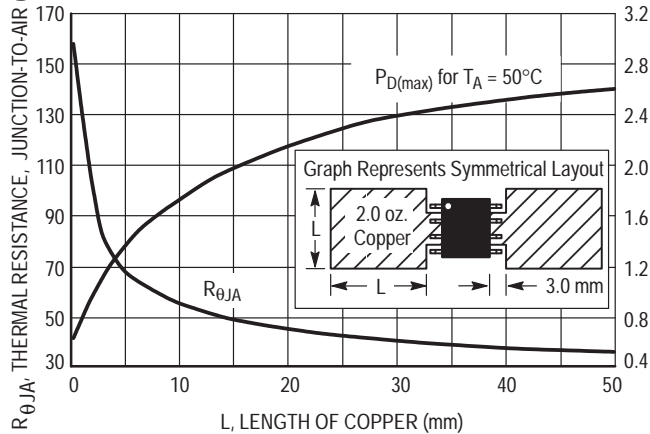


Figure 25. SOP-8 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length



MC33375

ORDERING INFORMATION

MC33375ST-1.8T3	1.8 V (Fixed V)	1% Tolerance at $T_A = 25^\circ\text{C}$ 2% Tolerance at T_J from -40 to $+125^\circ\text{C}$	318E	SOT-223
MC33375ST-2.5T3	2.5 V (Fixed Voltage)		318E	SOT-223
MC33375D-2.5R2			751-5	SOP-8
MC33375ST-3.0T3	3.0 V (Fixed Voltage)		318E	SOT-223
MC33375D-3.0R2			751-5	SOP-8
MC33375ST-3.3T3	3.3 V (Fixed Voltage)		318E	SOT-223
MC33375D-3.3R2			751-5	SOP-8
MC33375ST-5.0T3	5.0 V (Fixed Voltage)		318E	SOT-223
MC33375D-5.0R2			751-5	SOP-8

DEVICE MARKING

Device	Version	Marking (1st line)
MC33375	1.8V	37518
MC33375	2.5V	37525
MC33375	3.0V	37530
MC33375	3.3V	37533
MC33375	5.0V	37550

TAPE AND REEL SPECIFICATIONS

Device	Reel Size	Tape Width	Quantity
MC33375D	13"	12mm embossed tape	2500 units
MC33375ST	13"	8mm embossed tape	4000 units

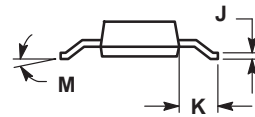
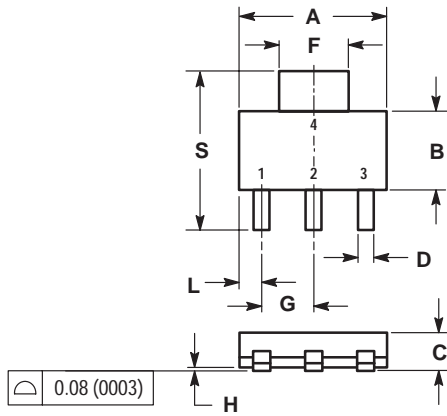
MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, for min/max values $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$)

Rating	Symbol	Value	Unit
Input Voltage	V_{CC}	13	Vdc
Power Dissipation and Thermal Characteristics $T_A = 25^\circ\text{C}$			
Maximum Power Dissipation	P_D	Internally Limited	W
Case 751 (SOP-8) D Suffix			
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	160	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	25	$^\circ\text{C/W}$
Case 318E (SOT-223) ST Suffix			
Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	245	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	15	$^\circ\text{C/W}$
Output Current	I_O	300	mA
Maximum Junction Temperature	T_J	150	$^\circ\text{C}$
Operating Junction Temperature Range	T_J	- 40 to +125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to +150	$^\circ\text{C}$

MC33375

PACKAGE DIMENSIONS

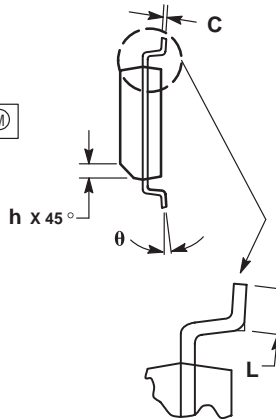
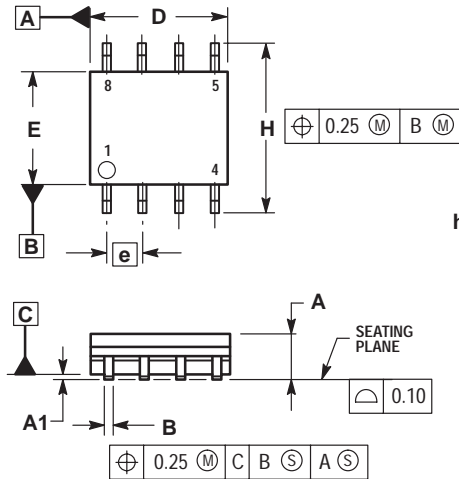
ST SUFFIX PLASTIC PACKAGE CASE 318E-04 (SOT-223) ISSUE J



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.249	0.263	6.30	6.70
B	0.130	0.145	3.30	3.70
C	0.060	0.068	1.50	1.75
D	0.024	0.035	0.60	0.89
F	0.115	0.126	2.90	3.20
G	0.087	0.094	2.20	2.40
H	0.0008	0.0040	0.020	0.100
J	0.009	0.014	0.24	0.35
K	0.060	0.078	1.50	2.00
L	0.033	0.041	0.85	1.05
M	0°	10°	0°	10°
S	0.264	0.287	6.70	7.30

D SUFFIX PLASTIC PACKAGE CASE 751-06 (SOP-8) ISSUE T



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. DIMENSIONS ARE IN MILLIMETER.
 3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.35	0.49
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.25
θ	0°	7°

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Spanish Phone: 303-308-7143 (Mon-Fri 8:00am to 5:00pm MST)
Email: ONlit-spanish@hibbertco.com

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support

Phone: 303-675-2121 (Tue-Fri 9:00am to 1:00pm, Hong Kong Time)
 Toll Free from Hong Kong & Singapore:
001-800-4422-3781
Email: ONlit-asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center
 4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-8549

Phone: 81-3-5740-2745
Email: r14525@onsemi.com

ON Semiconductor Website: <http://onsemi.com>

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